

INFORMATION

PRODUCT No. : Q22FA1280023800

MODEL : FA-128

INFO. No. : A12-436-8S

DATE : Aug. 30. 2012

SEIKO EPSON CORPORATION

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INTRODUCTION

1. The contents is subject to change without notice.
Please exchange the specification sheets regarding the product's warranty.
2. This sheet is not intended to guarantee or provide an approval of implementation of industrial patents.
3. We have prepared this sheet as carefully as possible.
If you find it incomplete or unsatisfactory in any respect, We would welcome your comments.

This product is compliant with RoHS Directive.

This Product supplied (and any technical information furnished, if any) by Seiko Epson Corporation shall not be used for the development and manufacture of weapon of mass destruction or for other military purposes.

Making available such products and technology to any third party who may use such products or technologies for the said purposes are also prohibited.

This product listed here is designed as components or parts for electronics equipment in general consumer use. We do not expect that any of these products would be incorporated or otherwise used as a component or part for the equipment, which requires an extra high reliability, such as satellite, rocket and other space systems, and medical equipment, the functional purpose of which is to keep life.

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[1] Absolute maximum ratings

No.	Parameter	Rating value	Note
1	Storage temperature	-40 °C to +125 °C	Suppose to be within CI std. at +25 °C ± 3 °C

[2] Operating range

No.	Parameter	Symbol	Value		
			Min.	Typ.	Max.
1	Operating temperature	T_use	-40 °C	—	+85 °C
2	Drive level	DL	10 μW	—	100 μW

[3] Electrical characteristics

No.	Parameter	Symbol	Standard	Conditions
1	Nominal frequency	f ₀	25 MHz	Fundamental
2	Frequency tolerance	f _{tol}	$\pm 30 \times 10^{-6}$	CL= 18 pF T _{use} = +25 °C±3 °C Drive level : 100 μW Not include aging
3	Motional resistance	R ₁	80 Ω Max.	π circuit JIS C6701 Drive level : 100 μW T _{use} = -40 °C to +85 °C
4	Shunt capacitance	C ₀	3.0 pF Max.	
5	Frequency versus temperature characteristics	f _{tem}	$\pm 30 \times 10^{-6}$	T _{use} = -40 °C to +85 °C (Ref. at +25 °C±3 °C) Drive level : 100 μW
6	Isolation resistance	IR	500 MΩ Min.	DC 100V × 60 sec. Between each terminals
7	Aging	f _{age}	$\pm 1 \times 10^{-6}$ /year	T _{use} = +25 °C±3 °C Drive level : 100 μW

[4] Environmental and mechanical characteristics

Item No.3 to No.6 shall be tested after following pre conditioning.

Pre conditioning : Test crystal must be leaving in room temperature for 24 h after reflow × 3.

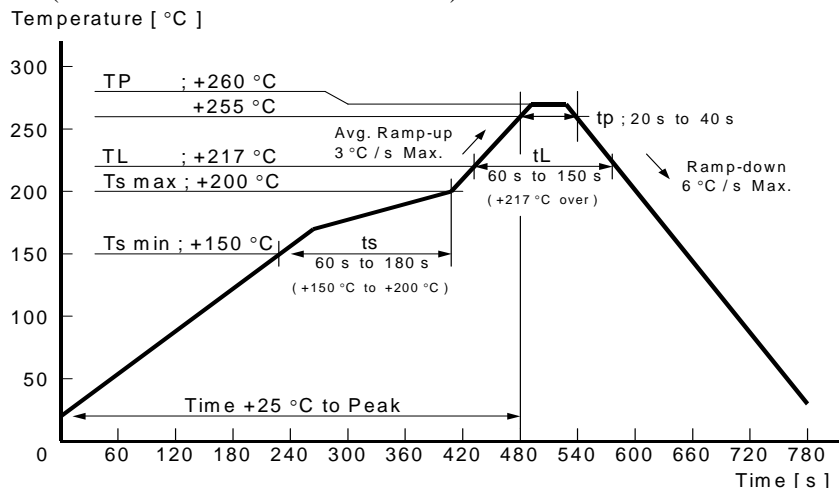
(The company evaluation condition : We evaluate it by the following examination item and examination condition.)

No.	Item	Value *1 *2		Test Conditions
		$\Delta f / f [1 \times 10^{-6}]$		
1	Drop	*3	±2	150 g dummy Jig (SE Standard) drop from 1500 mm height on the Concrete 6 directions 10 times
2	Vibration	*3	±2	10 Hz to 55 Hz amplitude 0.75 mm 55 Hz to 500 Hz acceleration 98 m/s ² 10 Hz → 500 Hz → 10 Hz 15 min./cycle 6 h (2 hours , 3 directions)
3	High temperature storage	*3	±2	+85 °C × 1 000 h
4	Low temperature storage	*3	±2	-40 °C × 1 000 h
5	Temperature cycle	*3	±2	-40 °C ↔ +85 °C 30 minutes at each temp. 100 cycle
6	Temperature humidity storage	*3	±2	+85 °C × 85 %RH × 1 000 h
7	Resistance to soldering heat		± 2	For convention reflow soldering furnace (3 times)
8	Substrate bending	No peeling-off at a soldered part		Bend width reaches 3 mm and hold for 5 s ± 1 s × 1 time Ref. IEC 60068-2-21
9	Shear	No peeling-off at a soldered part		10 N press for 10 s ± 1 s Ref. IEC 60068-2-21
10	Pull – off	No peeling-off at a soldered part		10 N press for 10 s ± 1 s Ref. IEC 60068-2-21
11	Solder ability	Terminals must be 95 % covered With fresh solder.		Dip termination into solder bath at +235 °C ± 10 °C for 5 s (Using Rosin Flux)

< Notes >

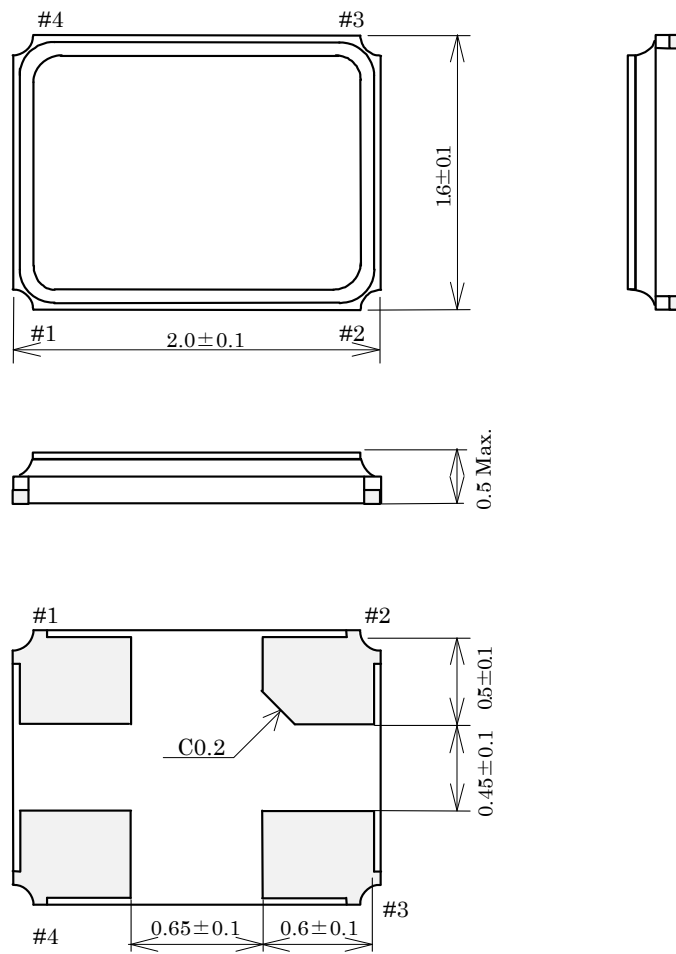
- *1 each test done independently.
- *2 measuring 2 h to 24 h later leaving in room temperature after each test.
- *3 Item No.1 to No.6 shall be tested after following pre conditioning.
- Item No.1 to No.11 resistance at before above tests should be less than ±20 % or less than ±10 Ω.
- Pre conditioning : Test crystal must be leaving in room temperature for 24h after reflow × 3.

Reflow condition (follow to IPC / JEDEC J-STD-020C)



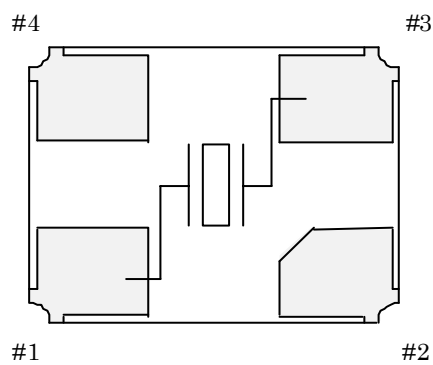
[5] Dimensions and Circuit

1) Dimension



2) Circuit

(Top View)



Pin connection

#1, #3: X'tal

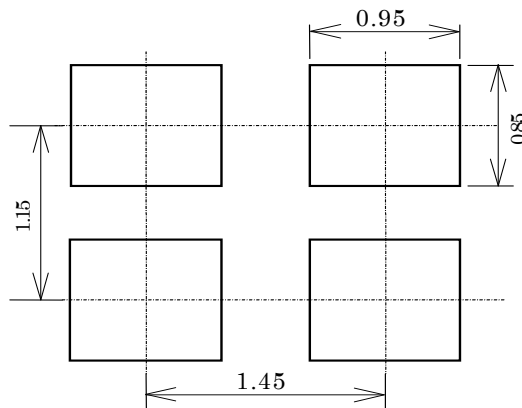
#2, #4: GND

Type	FA-128	Terminal treatment	Au plate	Unit	1 = 1mm
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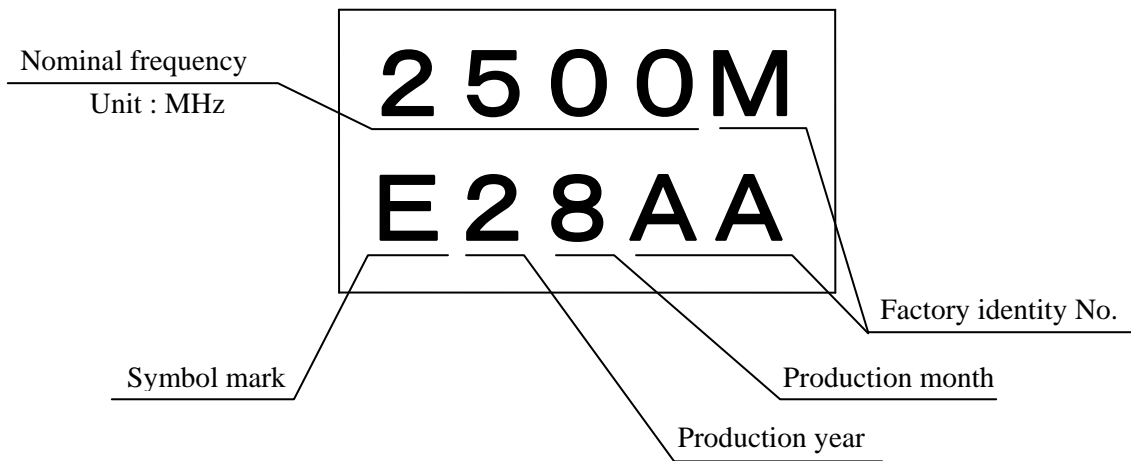
[6] Recommended soldering pattern and Marking layout

1) Recommended soldering pattern

Unit : mm



2) Marking layout



Production month

January	February	October	November	December
1	2	X	Y	Z

- Nominal frequency is only one example.
- Nominal frequency omits the figure below the second place of decimals.
ex) 25 MHz [2500]
- The above marking layout shows only marking contents and their approximate position and it is not for font, size and exact position.

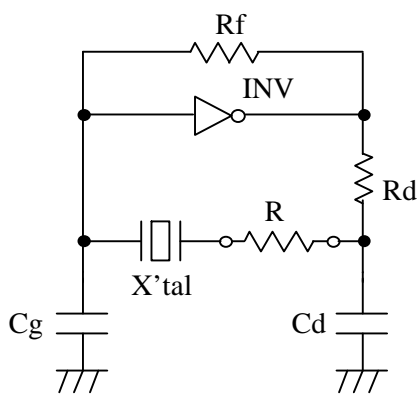
Type : FA-128

Unit : 1 = 1mm

[7] Notes

1. Max three (3) times re-flow is allowed. Its recommended to manually solder when not enough/no solder detected.(Using soldering iron at +350 °C × within 5 seconds)
2. Patterning on a board should follow our company recommended pattern.
3. Applying excessive excitation force to the crystal unit may cause deterioration damage.
4. Start up time of oscillation may be increased or no oscillation may occur unless adequate negative resistance is allocated in the oscillation circuit In order to avoid this, please provide enough negative resistance to the circuit design.

How to check the negative resistance



- (1) Connect the resistor(R) to the circuit in series with the crystal unit.
- (2) Adjust R so that oscillation can start (or stop).
- (3) Measure R when oscillation just start (or stop) in above (2).
- (4) Get the negative resistance
-R=R+CI value.
- (5) Recommended -R
[-R]>CI × 5

5. It is recommended to do patterning to the oscillator as short as possible. Abnormal oscillation may happened if the line is too long.
6. To avoid malfunction, no pattern across or near the crystal unit is allowed.
7. Few data or readings taken at user side may be different from our company's data. Confirmation of the different value is necessary before application.
8. Too much exciting shock or vibration may cause deterioration on damage.
The product may damage depends on the condition such as a shock in assembly machinery.
Please check your process condition in advance to minimize and maintain the shock level.
9. This product may be affected to ultrasonic cleaning. It is depends on the cleaning conditions (Cleaning machine type/power/time/content/position etc.). The warranty will not cover any damage due to this type of usage. Check conditions prior to use.
10. Condensation may occur when used/stored under high humidity condition.
Please take precautions to prevent condensation.
11. Please refer to packing specification for the storage method and packing standard.

TAPING SPECIFICATION

1. APPLICATION

This document is applicable to FA-128

2. CONTENTS

Item No.	Item	Page
[1]	Taping specification	1 to 2
[2]	Inner carton	3
[3]	Shipping carton	
[4]	Marking	4
[5]	Quantity	
[6]	Storage environment	
[7]	Handling	

[1] Taping specification

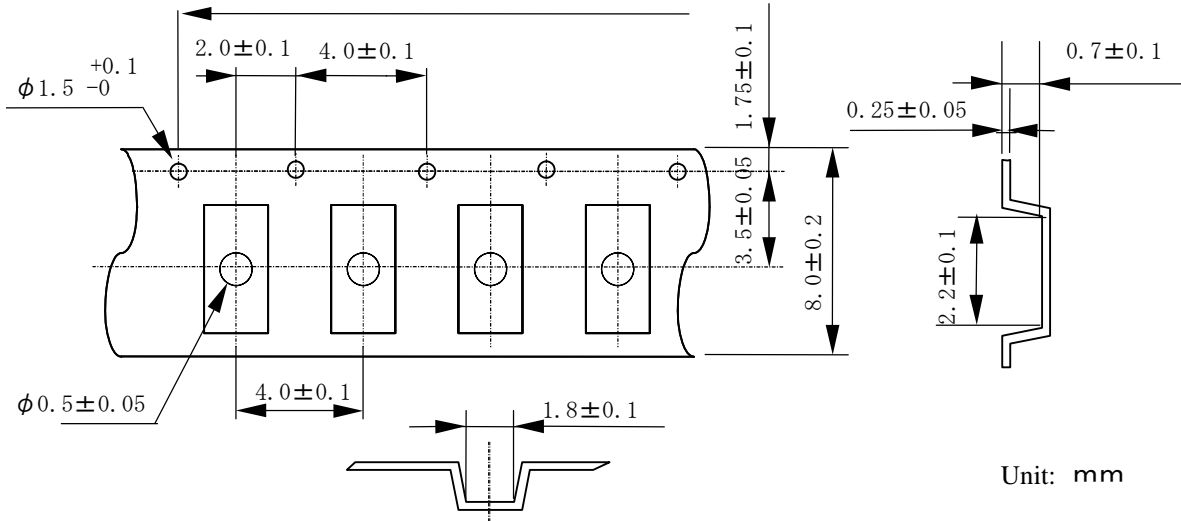
Subject to EIA-481 & IEC-60286

(1) Tape dimensions TE0804L

Material of the Carrier Tape : PS

Material of the Top Tape : PET+PE

10P : 40 ± 0.15

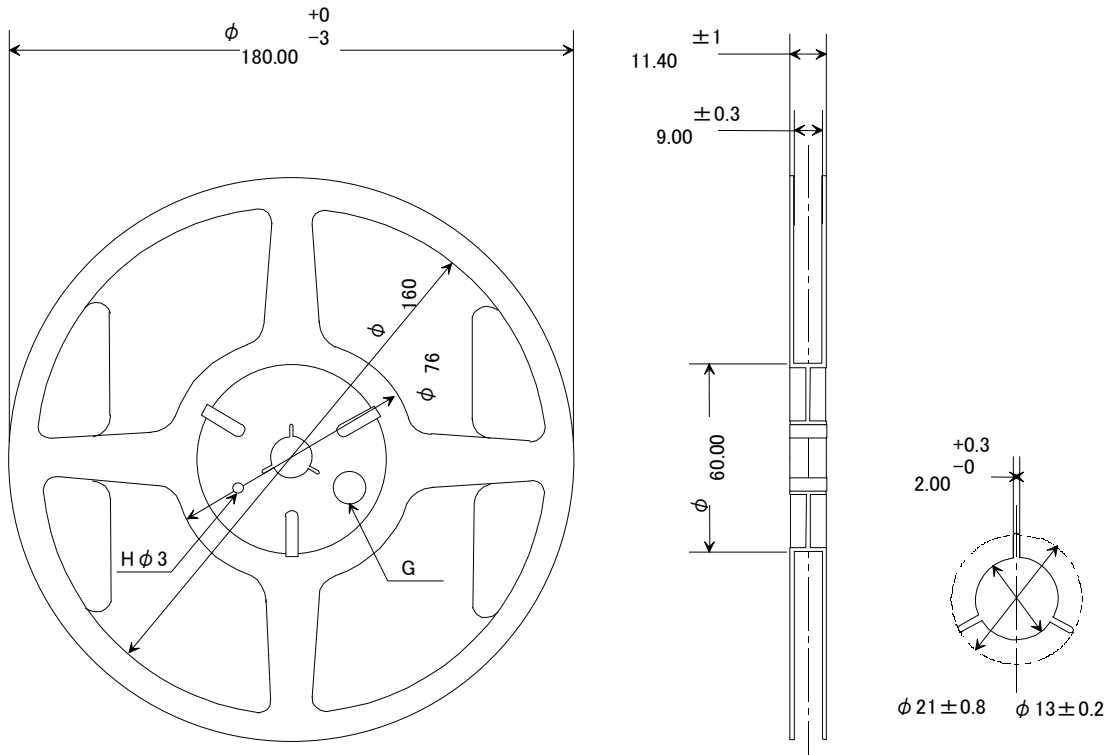


Unit: mm

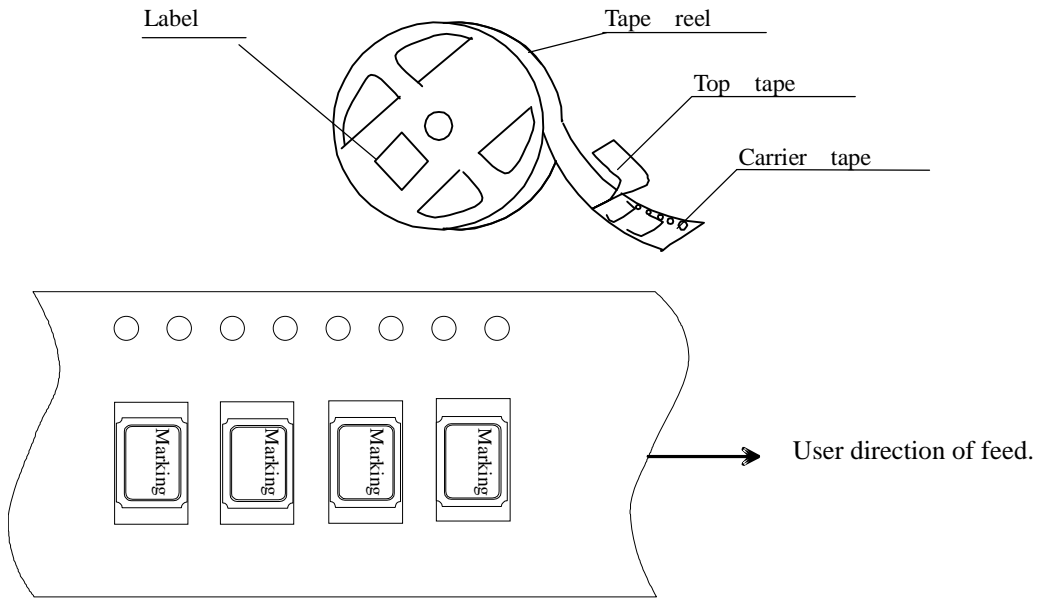
(2) Reel dimensions

(a) Center material : PS

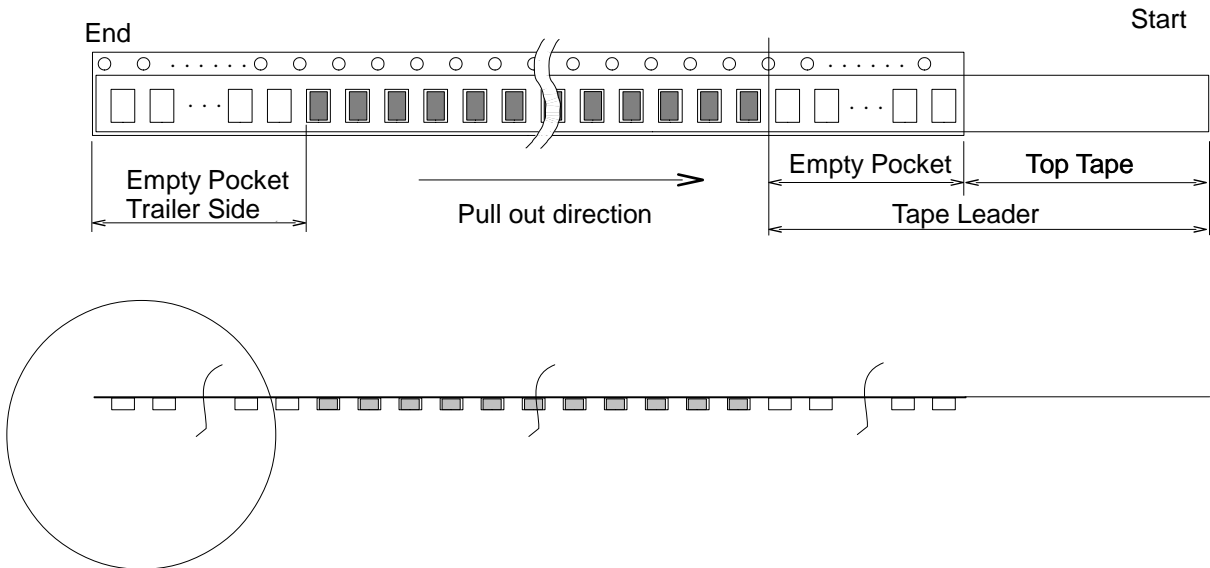
(b) Material of the Reel : PS



(3) Packing
(a) Tape & Reel



(b) Start & End Point



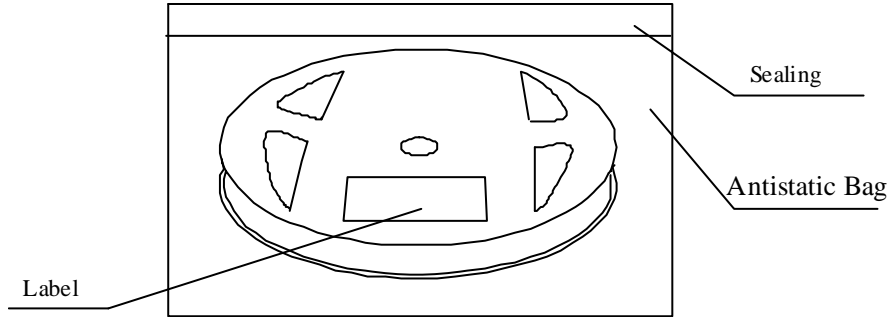
Item		Empty Space
Tape Leader	Top Tape	Min. 1 000 mm
	Carrier Tape	Min. 100 mm
Tape Trailer	Top Tape	Min. 0 mm
	Carrier Tape	Min. 160 mm

(4) Peel force of the cover tape

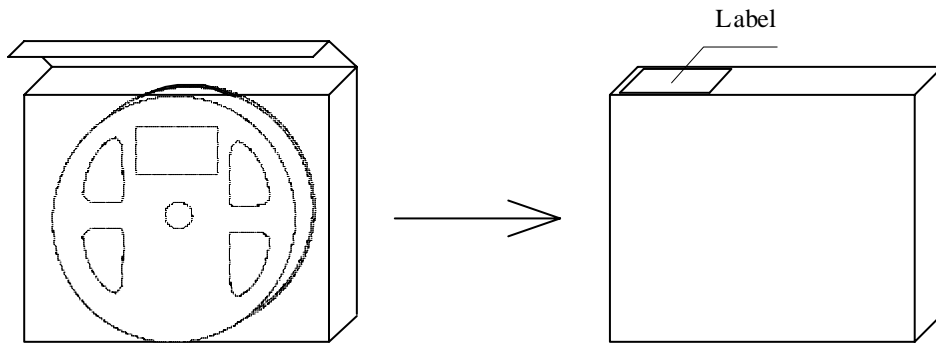
- ① angle : cover tape during peel off and the direction of unreeling shall be 165° to 180°.
- ② peel speed : 300 mm / min.
- ③ strength : 0.1 to 1 N.

[2] Inner Carton

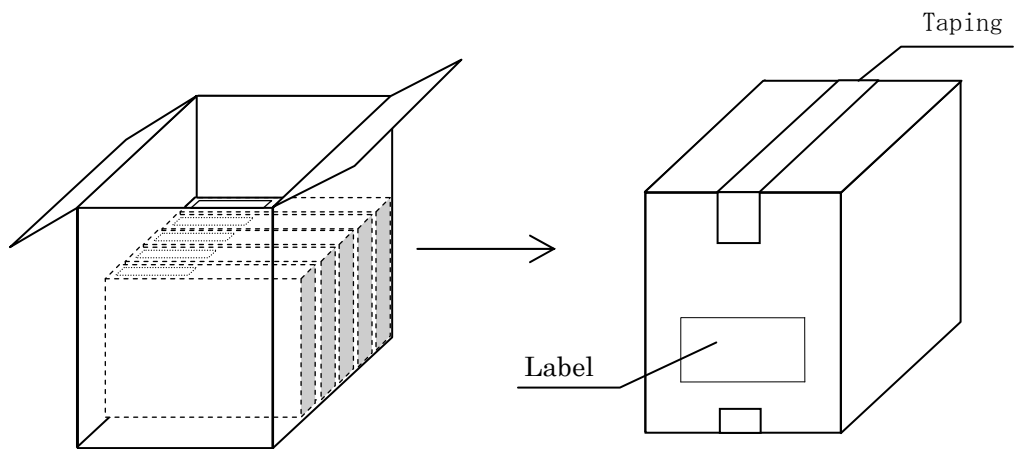
a) Packing to antistatic bag



b) Packing to inner carton



[3] Shipping Carton



[4] Marking

- (1) Reel marking
 - Reel marking shall consist of :
 - 1) Parts name
 - 2) Quantity
 - 3) Manufacturing Date or symbol
 - 4) Manufacturer's Date or symbol
 - 5) Others (if necessary)
- (2) Inner carton marking
 - Same as Reel marking.
- (3) Shipping carton marking
 - Shipping carton marking shall consist of :
 - 1) Parts name
 - 2) Quantity

[5] Quantity

- 3 000 pcs./reel

[6] Storage environment

- (1) To storage the reel at +15 °C to +35 °C , 25 %RH to 85 %RH of Humidity.
- (2) To open the packing just before using.
- (3) Not to expose the sun.
- (4) Not to storage with some erosive chemicals.
- (5) Nothing is allowed to put on the reel or carton to prevent mechanical damage.

[7] Handling

To handle with care to prevent the damage of tape, reel and products.

- Process Quality Control -

No. I-0502-01-AIE-3

SMD TYPE AT STRIP CRYSTAL : FA-128

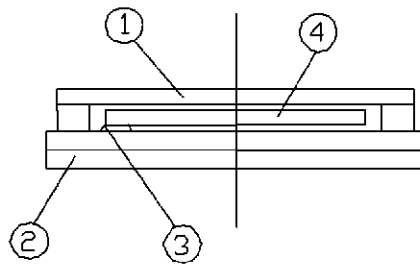
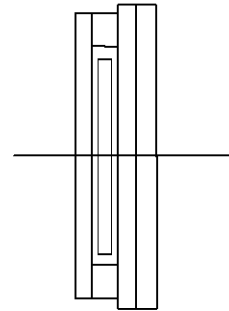
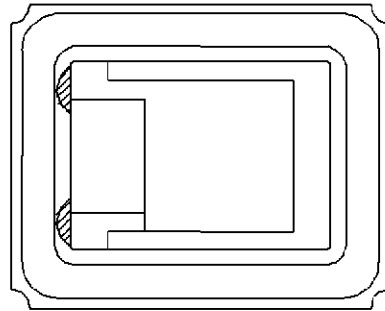
11.10.21

Manufacturing process chart		No.	Section	Standard	Inspection, Control items	Inspection method	Instrument	Record
	Crystal block	1	Inspecting section. (Ina / Miyazaki Plant)	Purchasing specification Incoming inspection standard	Size. Outer appearance. Inner appearance.	Sampling. " "	Measure. Visual inspection. Visual inspection.	In-coming inspection data sheet.
	In-coming inspection	1'	Inspecting section. (Ina / Thailand / Malaysia Plant)	"	Size. Outer appearance.	Sampling. "	Comparator. Micro scope.	"
	Wafer cutting	2	Inspecting section. (Ina / Miyazaki Plant)	Manufacturing instruction sheet	Cut angle. Wafer thickness.	Sampling. "	X-ray raiddo grafic. Comparator.	Process data sheet.
	Wafer lapping	3	Producing section. (Ina / Miyazaki Plant)	"	Frequency. Wafer thickness.	Sampling. "	Frequency counter. Comparator.	"
	Photo process	4	Producing section. (Ina / Miyazaki Plant)	"	Size. Frequency. Outer appearance.	Sampling. " "	Comparator. Frequency counter. Micro scope.	"
	Mounting	5	Producing section. (Ina / Thailand / Malaysia Plant)	"	Outer appearance.	All insprcion.	Micro scope.	"
	Frequency adjustment	6	Producing section. (Ina / Thailand / Malaysia Plant)	"	Frequency.	Sampling.	Network analyzer.	"
	Welding	7	Producing section. (Ina / Thailand / Malaysia Plant)	"	Outer appearance.	Sampling.	Micro scope.	"
	Leak test	8	Producing section. (Ina / Thailand / Malaysia Plant)	"	Airtightness check.	All insprcion.	Leak tester.	"
	Marking	9	Producing section. (Ina / Thailand / Malaysia Plant)	"	Outer appearance.	Sampling.	Micro scope.	"
	Characteristic inspection	10	Producing section. (Ina / Thailand / Malaysia Plant)	"	Crystal impedance. Frequency. Insulation resistance. Temp. characteristic. Outer appearance.	All insprcion. " " Sampling. All insprcion.	Inspectional machine. " " " Micro scope.	"
	Out-going inspection	11	Inspecting section. (Ina / Thailand / Malaysia Plant)	Out-going inspection standard	Crystal impedance. Frequency. Insulation resistance. Outer appearance.	Sampling. " " "	Inspection M/C. " " Micro scope.	Out-going inspection data sheet.
	Taping	12	Producing section. (Ina / Thailand / Malaysia Plant)	Manufacturing instruction sheet	Tape-peel strength.	Sampling.	Peelinf force tester.	Process data sheet.
Packing	13	Product control section. (Ina / Thailand / Malaysia Plant)	Manufacturing instruction sheet Packing instruction sheet	Address. Quantity.	—	—	Delivery slip.	

F A - 1 2 8 Construction Drawing

No. : A-0502-AE-1

Unit : mm



No	Parts NAME	Material	Surface Treatment
①	LID	Covar	Ni Plating
②	BASE	Ceramic • Covar	Au Plating
③	Ag Paste	Bonding Paste of Electric Conductor	
④	Crystal Chip	Crystal	Electrode Pattern(Cr+Au)

RELIABILITY TEST DATA
Product Name : FA-128

The Company evaluation condition
 We evaluate environmental and mechanical characteristics by the following test condition .

No.	ITEM	TEST CONDITIONS	VALUE *1 *2	TEST	FAIL
			$\Delta f / f$ [1 × 10 ⁻⁶]	Qty [n]	Qty [n]
1	Drop	150 g dummy Jig (Epsontoyocom Standard) drop from 1500 mm height on the Concrete 6 directions 10 times	*3 ± 2	22	0
2	Vibration	10 Hz to 55 Hz amplitude 0.75 mm 55 Hz to 500 Hz acceleration 98 m/s ² 10 Hz → 500 Hz → 10 Hz 15 min / cycle 6 h (2 h × 3 directions)	*3 ± 2	22	0
3	High temperature storage	+85 °C × 1 000 h	*3 ± 2	22	0
4	Low temperature storage	-40 °C × 1 000 h	*3 ± 2	22	0
5	Temperature cycle	-40 °C ↔ + 85 °C 30 min at each temp. 100 cycles	*3 ± 2	22	0
6	Temperature humidity storage	+85 °C × 85 %RH × 1 000 h	*3 ± 2	22	0
7	Resistance to soldering heat	For convention reflow soldering furnace (3 times)	± 2	22	0
8	Substrate bending	Bend width reaches 3.0 mm and hold for 5 s ± 1 s × 1 time Ref. IEC 60068-2-21	No peeling - off at a solder part	11	0
9	Shear	10 N press for 10 s ± 1 s Ref. IEC 60068-2-21	No peeling - off at a solder part	11	0
10	Pull - off	10 N press for 10 s ± 1 s Ref. IEC 60068-2-21	No peeling - off at a solder part	11	0
11	Solderability	Dip termination into solder bath at +235°C ± 10 °C for 5 s (Using Rosin Flux)	Termination must be 95 % covered with fresh solder	11	0

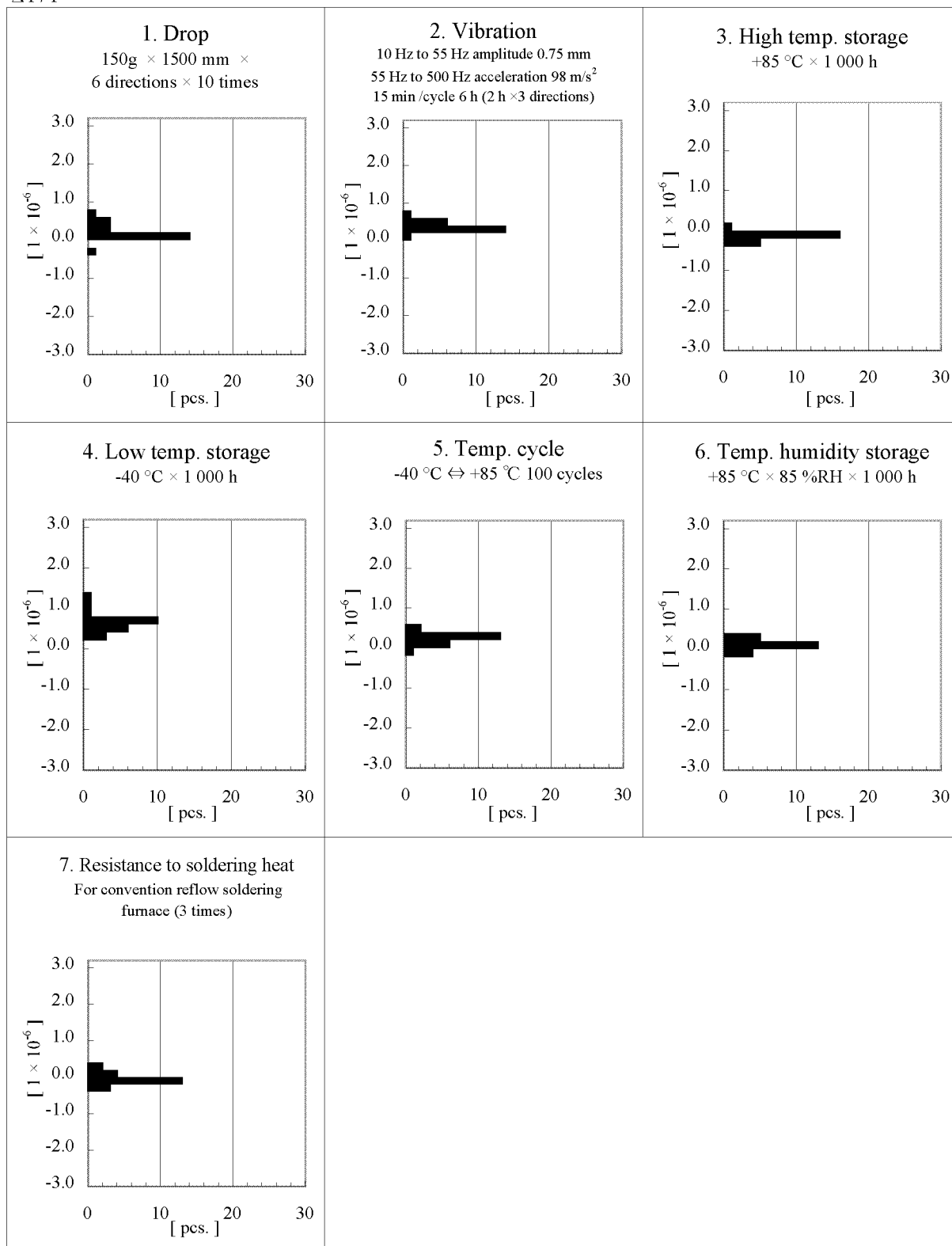
Notes

1. *1 Each test done independently.
2. *2 Measuring 2 h to 24 h later leaving in room temperature after each test.
3. *3 Measuring 24 h later leaving in room temperature after each test.
 1. Reflow 3 times
 2. Initial value shall be after 24h at room temperature.
4. Shift series resistance at before above tests should be less than ±20 % or less than ±10 Ω.

Qualification Data

Product Name : FA-128

$\Delta f / f$



Qualification Data

Product Name : FA-128

ΔCI

